

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,015,547 B2
APPLICATION NO. : 10/613169
DATED : March 21, 2006
INVENTOR(S) : Douglas R. Hackler, Sr.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 3, line 33 "...FIG. 1..." change to --FIG. 1,--

Column 4, lines 23-24 "...coupling to the main bodies..." change to --coupling the main bodies--

Column 5, line 2, "...material of the first. ..." change to --material as the first--

Column 5, line 11 "...as a STI oxide,..." change to --as an STI oxide,--

Column 7, line 41 "...A SOI layer..." change to --An SOI layer--

Column 7, line 45 "...form a N+..." change to --form an N+--

Column 8, line 44 "...38,40." change to --38, 40.--

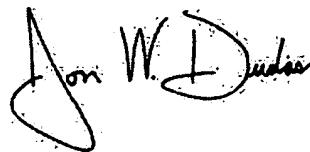
Column 8, line 53 "...spacer 48, 50." change to --spacers 48,50.--

Column 11, line 28 "...the drain and and proximate..." change to --the drain and proximate--

Column 12, line 16 "...gate insulator and top..." change to --gate insulator, and --

Signed and Sealed this

Second Day of January, 2007



JON W. DUDAS
Director of the United States Patent and Trademark Office